



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic | Symbol              | Value      | Unit |
|----------------|---------------------|------------|------|
| Supply Voltage | V <sub>CC</sub>     | 50         | V    |
| Input Voltage  | V <sub>IN</sub>     | -10 to +40 | V    |
| Output Current | I <sub>C(MAX)</sub> | 100        | mA   |

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                       | Symbol                            | Value       | Unit |
|------------------------------------------------------|-----------------------------------|-------------|------|
| Power Dissipation (Notes 5 & 6)                      | P <sub>D</sub>                    | 150         | mW   |
| Thermal Resistance, Junction to Ambient Air (Note 5) | R <sub>θJA</sub>                  | 833         | °C/W |
| Operating and Storage Temperature Range              | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                       | Symbol               | Min  | Typ | Max  | Unit | Test Condition                                           |
|--------------------------------------|----------------------|------|-----|------|------|----------------------------------------------------------|
| Collector-Base Breakdown Voltage     | BV <sub>CBO</sub>    | 50   | —   | —    | V    | I <sub>C</sub> = 50μA                                    |
| Collector-Emitter Breakdown Voltage  | BV <sub>CEO</sub>    | 50   | —   | —    | V    | I <sub>C</sub> = 1mA                                     |
| Emitter-Base Breakdown Voltage       | BV <sub>EBO</sub>    | 5    | —   | —    | V    | I <sub>E</sub> = 50μA                                    |
| Collector Cutoff Current             | I <sub>CBO</sub>     | —    | —   | 0.5  | μA   | V <sub>CB</sub> = 50V                                    |
| Emitter Cutoff Current               | I <sub>EBO</sub>     | —    | —   | 0.5  | μA   | V <sub>EB</sub> = 4V                                     |
| Collector-Emitter Saturation Voltage | V <sub>CE(sat)</sub> | —    | —   | 0.3  | V    | I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA             |
| DC Current Transfer Ratio            | h <sub>FE</sub>      | 100  | 250 | 600  | —    | I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V               |
| Input Resistor (R <sub>1</sub> )     | R <sub>1</sub>       | 32.9 | 47Ω | 61.1 | kΩ   | —                                                        |
| Gain-Bandwidth Product (Note 7)      | f <sub>T</sub>       | —    | 250 | —    | MHz  | V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz |

Notes: 5. Mounted on FR4 PC Board with minimum recommended pad layout.  
6. 200mW per element must not be exceeded.  
7. Transistor - For Reference Only

**Typical Curves** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

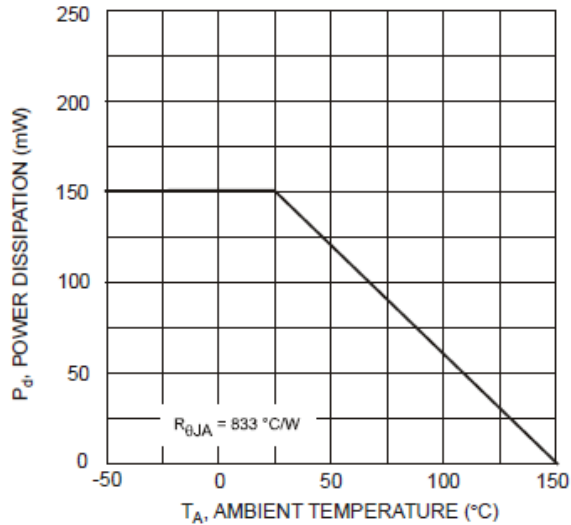


Fig. 1 Derating Curve

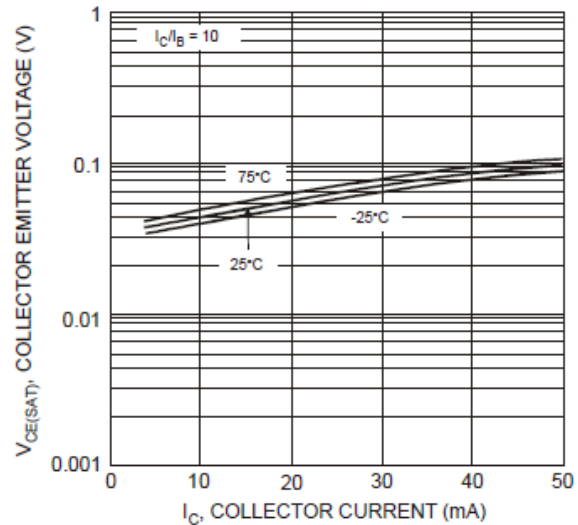


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

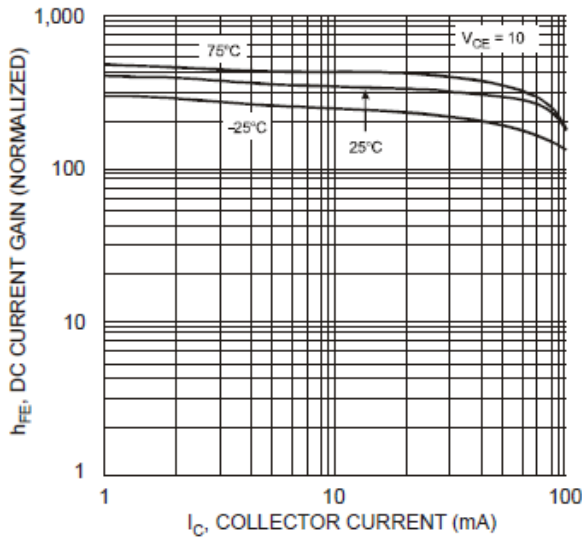


Fig. 3 DC Current Gain

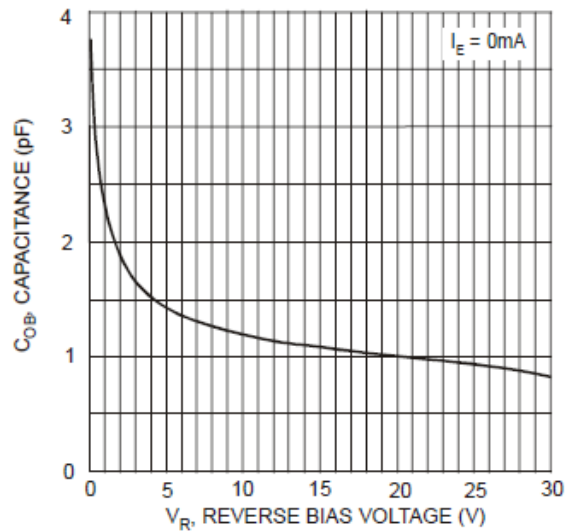


Fig. 4 Output Capacitance

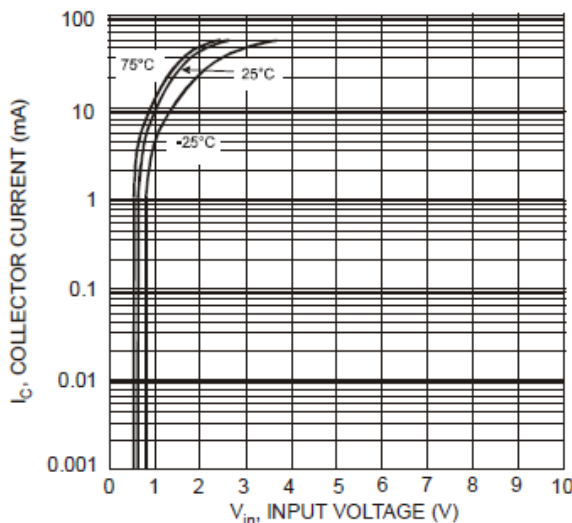


Fig. 5 Collector Current vs. Input Voltage

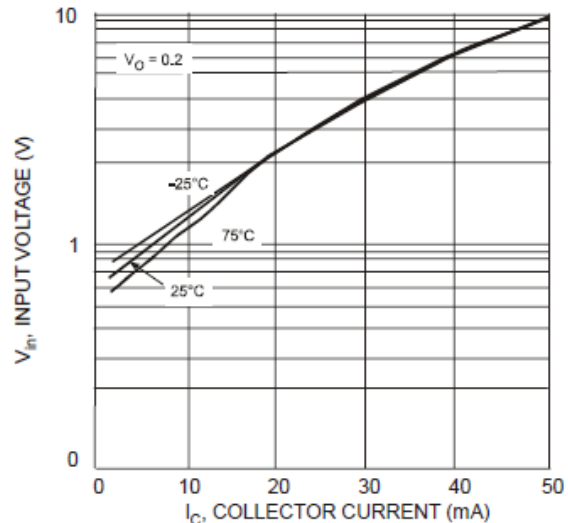
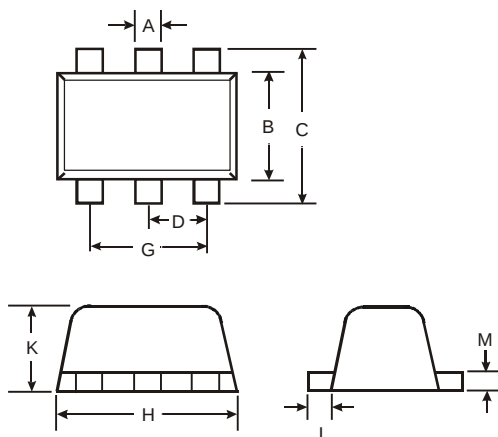


Fig. 6 Input Voltage vs. Collector Current

## Package Outline Dimensions

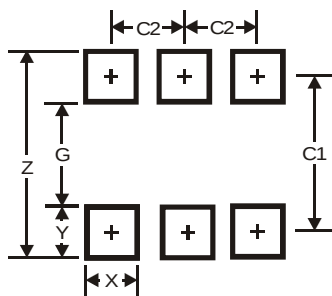
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| SOT563               |      |      |      |
|----------------------|------|------|------|
| Dim                  | Min  | Max  | Typ  |
| A                    | 0.15 | 0.30 | 0.20 |
| B                    | 1.10 | 1.25 | 1.20 |
| C                    | 1.55 | 1.70 | 1.60 |
| D                    | -    | -    | 0.50 |
| G                    | 0.90 | 1.10 | 1.00 |
| H                    | 1.50 | 1.70 | 1.60 |
| K                    | 0.55 | 0.60 | 0.60 |
| L                    | 0.10 | 0.30 | 0.20 |
| M                    | 0.10 | 0.18 | 0.11 |
| All Dimensions in mm |      |      |      |

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z          | 2.2           |
| G          | 1.2           |
| X          | 0.375         |
| Y          | 0.5           |
| C1         | 1.7           |
| C2         | 0.5           |

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